

FQU4N20TU

FQU4N20TU Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



FQU4N20TU Specifications

Manufacturer Part Number	FQU4N20TU
Manufacturer	Fairchild/ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-251-3 Short Leads, IPak, TO-251AA
Series	QFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	3A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	5V, 10V
Vgs(th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.5nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	220pF @ 25V
Vgs (Max)	$\pm 20\mathrm{V}$
FET Feature	-
Power Dissipation (Max)	2.5W (Ta), 30W (Tc)
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 1.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	I-Pak
Package / Case	TO-251-3 Short Leads, IPak, TO-251AA
	Report errors?

FQU4N20TU Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

FQU4N20TU Payment Methods





If you have any question about FQU4N20TU, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com